N-Channel 100-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

ESD Protected 2000V

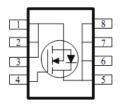
PRODUCT SUMMARY					
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)			
100	78 @ V _{GS} = 10V	5.2			
	92 @ V _{GS} = 4.5V	4.8			

Typical Applications:

- PoE Power Sourcing Equipment
- PoE Powered Devices
- Telecom DC/DC converters
- · White LED boost converters







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)						
Parameter			Symbol	Limit	Units	
Drain-Source Voltage				100	V	
Gate-Source Voltage			V_{GS}	±20	V	
Continuous Durin Commental		T _A =25°C	ı	5.2	А	
Continuous Drain Current ^a		T _A =70°C	I _D	4.4		
Pulsed Drain Current ^b			I _{DM}	50		
Continuous Source Current (Diode Conduction) a			Is	3	Α	
Daway Dissinction ^a		T _A =25°C T _A =70°C	P _D	3.1	W	
Power Dissipation ^a		T _A =70°C	гD	2.2	V V	
Operating Junction and Storage Temperature Range				-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	40	°C/W		
Maximum Junction-to-Ambient	Steady State	IN _θ JΑ	80	C/VV		

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

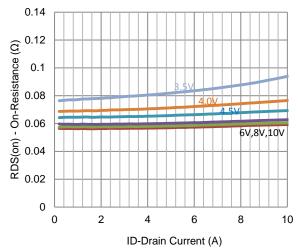
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$			3.5	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±10	uA	
Zero Gate Voltage Drain Current	1	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Brain Current	I _{DSS}	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α	
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_D = 3.6 \text{ A}$			78	mΩ	
Dialii-Source Off-Resistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 3.3 \text{ A}$			92		
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 3.6 \text{ A}$		20		S	
Diode Forward Voltage	V_{SD}	$I_{S} = 1.5 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V	
	Dynamic						
Total Gate Charge	Q_g			17.7		nC	
Gate-Source Charge	Q_gs	$V_{DS} = 50 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 3.6 \text{ A}$		2.7			
Gate-Drain Charge	Q_{gd}			11.1			
Turn-On Delay Time	t _{d(on)}			7			
Rise Time	t _r	$V_{DD} = 50 \text{ V}, R_L = 13.9 \Omega, I_D = 3.6 \text{ A},$		5.8		ns	
Turn-Off Delay Time	$t_{d(off)}$	V_{GEN} = 10 V, R_{GEN} = 6 Ω		46			
Fall-Time	t _f	1		26			
Input Capacitance	C _{iss}			990			
Output Capacitance	ut Capacitance C_{oss} $V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1$			115		pF	
Reverse Transfer Capacitance C _{rss}				77			

Notes

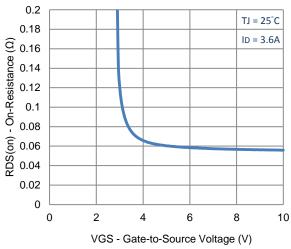
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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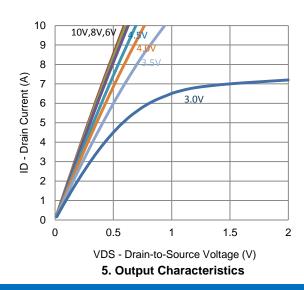
Typical Electrical Characteristics

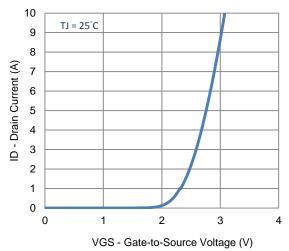


1. On-Resistance vs. Drain Current

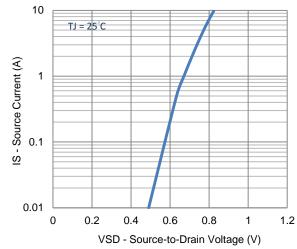


3. On-Resistance vs. Gate-to-Source Voltage

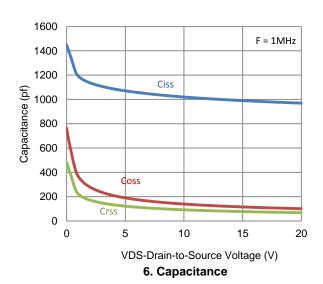




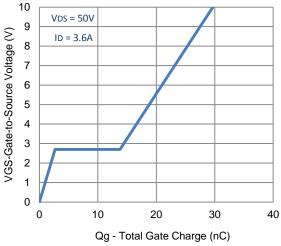
2. Transfer Characteristics



4. Drain-to-Source Forward Voltage



Typical Electrical Characteristics



TJ - Junction Temperature (°C)

80 60

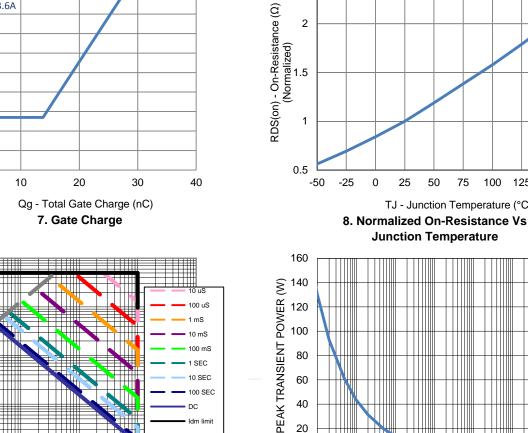
40 20

0

0.01

0.1

2.5



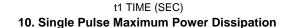
00 SEC

Limited by

1000

10 100 VDS Drain to Source Voltage (V)

9. Safe Operating Area



50

75

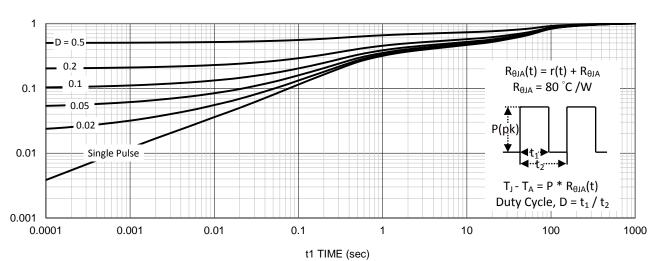
100

125 150

100

10

1000



11. Normalized Thermal Transient Junction to Ambient

100

10

0.1

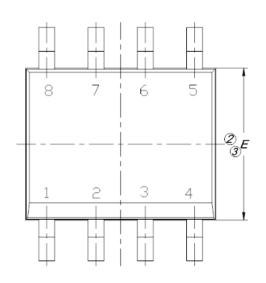
0.01

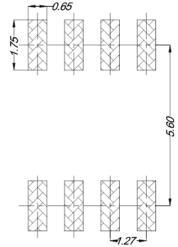
0.1

ID Current (A)

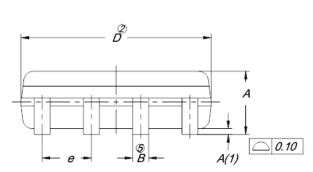
Package Information

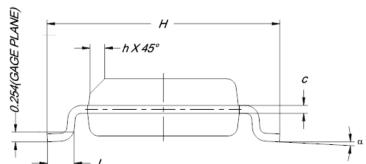
Land Pattern (Only for Reference)





DII.4	MILLIMETERS					
DIM.	MIN.	NOM.	MAX.			
Α	1.35	1.55	1.75			
A(1)	0.10	0.18	0.25			
В	0.38	0.45	0.51			
С	0.19	0.22	0.25			
D	4.80	4.90	5.00			
E	3.80	3.90	4.00			
е	1.27 BSC					
Н	5.80	6.00	6.20			
L	0.50	0.72	0.93			
α	0°	4°	8°			
h	0.25	0.38	0.50			





Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- 5. Dimension B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess Of B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.